Hex Non-Inverting 3-State Buffer

The MC14503B is a hex non–inverting buffer with 3–state outputs, and a high current source and sink capability. The 3–state outputs make it useful in common bussing applications. Two disable controls are provided. A high level on the Disable A input causes the outputs of buffers 1 through 4 to go into a high impedance state and a high level on the Disable B input causes the outputs of buffers 5 and 6 to go into a high impedance state.

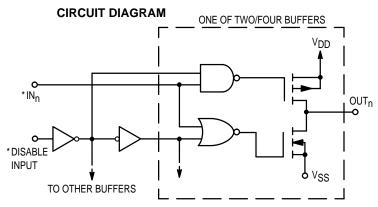
- 3-State Outputs
- TTL Compatible Will Drive One TTL Load Over Full Temperature Range
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Two Disable Controls for Added Versatility
- Pin for Pin Replacement for MM80C97 and 340097

MAXIMUM RATINGS* (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage	- 0.5 to + 18.0	V
V _{in} , V _{out}	Input or Output Voltage (DC or Transient)	-0.5 to $V_{DD} + 0.5$	٧
l _{in}	Input Current (DC or Transient), per Pin	± 10	mA
l _{out}	Output Current (DC or Transient), per Pin	± 25	mA
PD	Power Dissipation, per Package†	500	mW
T _{stg}	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

* Maximum Ratings are those values beyond which damage to the device may occur. †Temperature Derating:

Plastic "P and D/DW" Packages: - 7.0 mW/°C From 65°C To 125°C Ceramic "L" Packages: - 12 mW/°C From 100°C To 125°C



* Diode protection on all inputs (not shown)

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

MC14503B



L SUFFIX CERAMIC CASE 620



P SUFFIX PLASTIC CASE 648



D SUFFIX SOIC CASE 751B

ORDERING INFORMATION

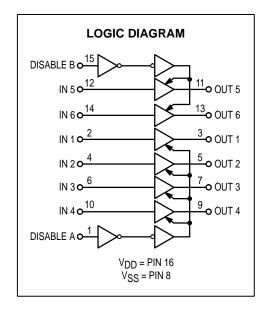
MC14XXXBCP Plastic MC14XXXBCL Ceramic MC14XXXBD SOIC

 $T_A = -55^{\circ}$ to 125°C for all packages.

TRUTH TABLE

Inn	Appropriate Disable Input	Outn
0	0	0
1	0	1
Х	1	High Impedance

X = Don't Care





ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

			V _{DD}	- 5	5°C		25°C		125	5°C	
Characteristic		Symbol	Vdc	Min	Max	Min	Typ #	Max	Min	Max	Unit
Output Voltage V _{in} = 0	"0" Level	VOL	5.0 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	Vdc
$V_{in} = V_{DD}$	"1" Level	VOH	5.0 10 15	4.95 9.95 14.95		4.95 9.95 14.95	5.0 10 15		4.95 9.95 14.95		Vdc
Input Voltage (V _O = 3.6 or 1.4 Vdc) (V _O = 7.2 or 2.8 Vdc) (V _O = 11.5 or 3.5 Vdc)	"0" Level	VIL	5.0 10 15	_ _ _	1.5 3.0 4.0	_ _ _	2.25 4.50 6.75	1.5 3.0 4.0	_ _ _	1.5 3.0 4.0	Vdc
(V _O = 1.4 or 3.6 Vdc) (V _O = 2.8 or 7.2 Vdc) (V _O = 3.5 or 11.5 Vdc)	"1" Level	VIH	5.0 10 15	3.5 7.0 11	_ _ _	3.5 7.0 11	2.75 5.50 8.25	_ _ _	3.5 7.0 11	_ _ _	Vdc
Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc)	Source	ЮН	4.5 5.0 5.0 10 15	- 4.3 - 5.8 - 1.2 - 3.1 - 8.2	_ _ _ _	- 3.6 - 4.8 - 1.02 - 2.6 - 6.8	- 5.0 - 6.1 - 1.4 - 3.7 - 14.1	_ _ _ _	- 2.5 - 3.0 - 0.7 - 1.8 - 4.8	_ _ _ _	mAdc
(V _{OL} = 0.4 Vdc) (V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc)	Sink	lOL	4.5 5.0 10 15	2.2 2.6 6.5 19.2	_ _ _	1.8 2.1 5.5 16.1	2.1 2.3 6.2 25	_ _ _ _	1.2 1.3 3.8 11.2	_ _ _	mAdc
Input Current		l _{in}	15	_	± 0.1	_	±0.00001	± 0.1	_	± 1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	_	_	_	_	5.0	7.5	_	_	pF
Quiescent Current (Per Package)		ΙQ	5.0 10 15	_ _ _	1.0 2.0 4.0	_	0.002 0.004 0.006	1.0 2.0 4.0	_ _ _	30 60 120	μAdc
Total Supply Current**† (Dynamic plus Quiescer Per Package) (C _L = 50 pF on all outpu (All outputs switching, 50% Duty Cycle)		ΙΤ	5.0 10 15			$I_T = (6$	5 μΑ/kHz) f 6.0 μΑ/kHz) f 10 μΑ/kHz) f	+ I _{DD}			μAdc
Three–State Output Leakag	ge	lTL	15	_	± 0.1	_	± 0.0001	± 0.1	_	± 3.0	μAdc

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μ A (per package), C_L in pF, V = (V_{DD} – V_{SS}) in volts, f in kHz is input frequency, and k = 0.006.

^{**}The formulas given are for the typical characteristics only at 25 $^{\circ}\text{C}.$

[†]To calculate total supply current at loads other than 50 pF:

SWITCHING CHARACTERISTICS* ($C_L = 50 \text{ pF}, T_A = 25^{\circ}C$)

		V _{DD}	All Types		
Characteristic	Symbol	VCC	Typ #	Max	Unit
Output Rise Time $t_{TLH} = (0.5 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{TLH} = (0.3 \text{ ns/pF}) C_L + 8.0 \text{ ns}$ $t_{TLH} = (0.2 \text{ ns/pF}) C_L + 8.0 \text{ ns}$	tтLH	5.0 10 15	45 23 18	90 45 35	ns
Output Fall Time $t_{THL} = (0.5 \text{ ns/pF}) \text{ C}_L + 20 \text{ ns}$ $t_{THL} = (0.3 \text{ ns/pF}) \text{ C}_L + 8.0 \text{ ns}$ $t_{THL} = (0.2 \text{ ns/pF}) \text{ C}_L + 8.0 \text{ ns}$	tTHL	5.0 10 15	45 23 18	90 45 35	ns
Turn–Off Delay Time, all Outputs tpLH = (0.3 ns/pF) C _L + 60 ns tpLH = (0.15 ns/pF) C _L + 27 ns tpLH = (0.1 ns/pF) C _L + 20 ns	^t PLH	5.0 10 15	75 35 25	150 70 50	ns
Turn-On Delay Time, all Outputs tpHL = (0.3 ns/pF) C _L + 60 ns tpHL = (0.15 ns/pF) C _L + 27 ns tpHL = (0.1 ns/pF) C _L + 20 ns	^t PHL	5.0 10 15	75 35 25	150 70 50	ns
3-State Propagation Delay Time Output "1" to High Impedance	[†] PHZ	5.0 10 15	75 40 35	150 80 70	ns
Output "0" to High Impedance	[†] PLZ	5.0 10 15	80 40 35	160 80 70	ns
High Impedance to "1" Level	[†] PZH	5.0 10 15	65 25 20	130 50 40	ns
High Impedance to "0" Level	[†] PZL	5.0 10 15	100 35 25	200 70 50	ns

PIN ASSIGNMENT

DIS A	1 ●	16] V _{DD}
IN 1 [2	15] DIS B
OUT 1	3	14] IN 6
IN 2 [4	13	OUT 6
OUT 2	5	12] IN 5
IN 3 [6	11] OUT 5
OUT 3	7	10] IN 4
V _{SS} [8	9	OUT 4

^{*} The formulas given are for the typical characteristics only at 25°C.
#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

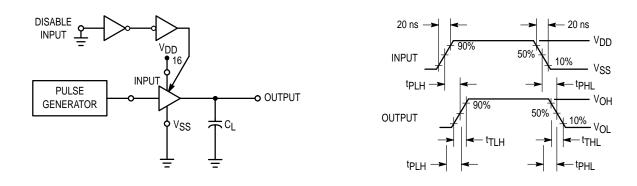


Figure 1. Switching Time Test Circuit and Waveforms (t_{TLH}, t_{THL}, t_{PHL}, and t_{PLH})

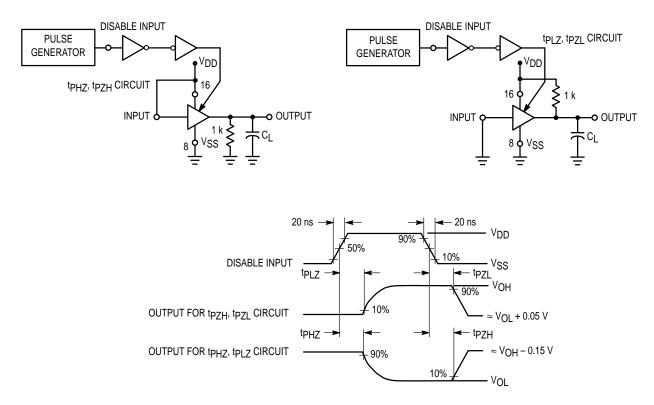
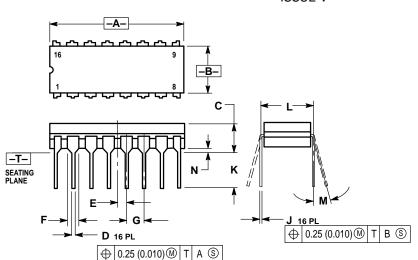


Figure 2. 3-State AC Test Circuit and Waveforms (tpLz, tpHz, tpZH, tpZL)

OUTLINE DIMENSIONS

L SUFFIX CERAMIC DIP PACKAGE CASE 620-10 ISSUE V



NOTES:

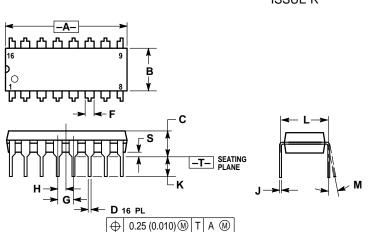
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 DIMENSION L TO CENTER OF LEAD WHEN
 FORMED PARALLEL.
 DIMENSION F MAY NARROW TO 0.76 (0.030)
 WHERE THE LEAD ENTERS THE CERAMIC

	INC	HES	MILLIN	IETERS	
DIM	MIN	MIN MAX		MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Е	0.050	BSC	1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100) BSC	2.54	BSC	
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300) BSC	7.62	BSC	
М	0°	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	

P SUFFIX PLASTIC DIP PACKAGE

CASE 648-08 ISSUE R



NOTES:

- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

 5. ROUNDED CORNERS OPTIONAL.

DIM	MIN	MAX			
		INITAL	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
М	0°	10°	0°	10 °	
S	0.020	0.040	0.51	1.01	

OUTLINE DIMENSIONS



- DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
М	0°	7°	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters which may be provided in Motorola data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and Marare registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

USA/EUROPE/Locations Not Listed: Motorola Literature Distribution; P.O. Box 20912: Phoenix. Arizona 85036. 1-800-441-2447 or 602-303-5454

MFAX: RMFAX0@email.sps.mot.com - TOUCHTONE 602-244-6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, 6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-81-3521-8315

ASIA/PACIFIC: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852-26629298





This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.